



SANYO Semiconductors

## DATA SHEET

An ON Semiconductor Company

# 15C01C — NPN Epitaxial Planar Silicon Transistor

## Low-Frequency General-Purpose Amplifier Applications

### Applications

- Low-frequency Amplifier, muting circuit

### Features

- Large current capacity
- Low collector-to-emitter saturation voltage (resistance)  $R_{CE(sat)}$  typ.= $0.58\Omega$  [ $I_C=0.7A$ ,  $I_B=35mA$ ]
- Ultrasmall package facilitates miniaturization in end products
- Small ON-resistance ( $R_{on}$ )

### Specifications

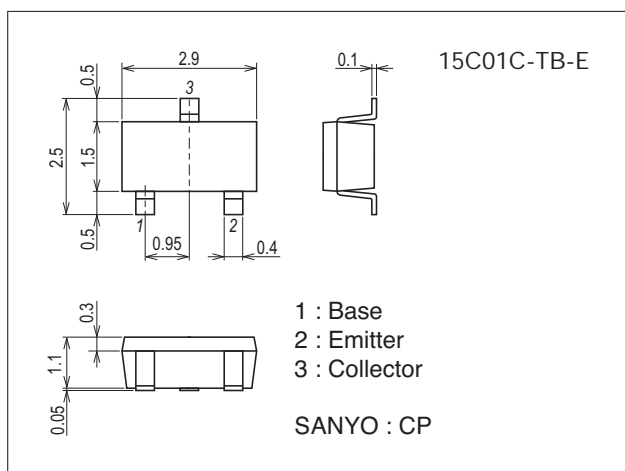
Absolute Maximum Ratings at  $T_a=25^\circ C$ 

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		20	V
Collector-to-Emitter Voltage	$V_{CEO}$		15	V
Emitter-to-Base Voltage	$V_{EBO}$		5	V
Collector Current	$I_C$		700	mA
Collector Current (Pulse)	$I_{CP}$		1.4	A
Collector Dissipation	$P_C$	Mounted on a glass epoxy board (20×30×1.6mm)	300	mW
Junction Temperature	$T_j$		150	$^\circ C$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ C$

### Package Dimensions

unit : mm (typ)

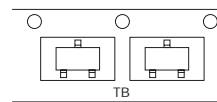
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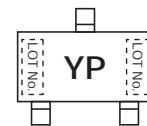
### Product & Package Information

- Package : CP
- JEITA, JEDEC : SC-59, TO-236, SOT-23, TO-236AB
- Minimum Packing Quantity : 3,000 pcs./reel

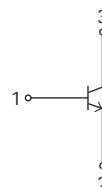
### Packing Type: TB



### Marking



### Electrical Connection

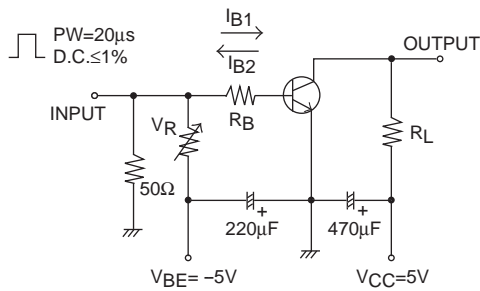


# 15C01C

## Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =15V, I <sub>E</sub> =0A			0.1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			0.1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =10mA	300		800	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =50mA		330		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		3.2		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =200mA, I <sub>B</sub> =10mA		150	300	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =200mA, I <sub>B</sub> =10mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =10μA, I <sub>E</sub> =0A	20			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	15			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10μA, I <sub>C</sub> =0A	5			V
Turn-On Time	t <sub>on</sub>	See specified Test Circuit.		30		ns
Storage Time	t <sub>stg</sub>			77		ns
Fall Time	t <sub>f</sub>			40		ns

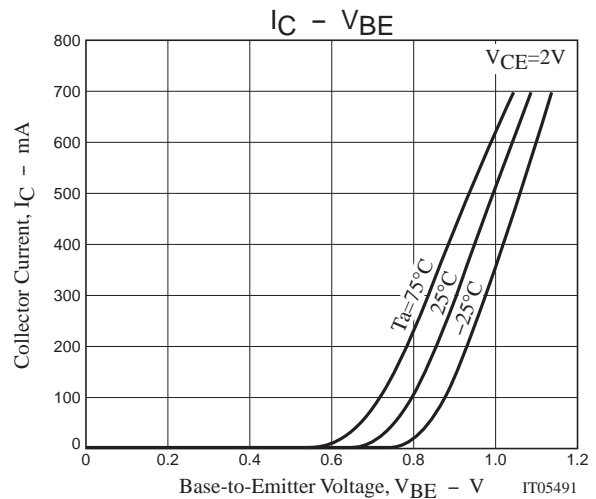
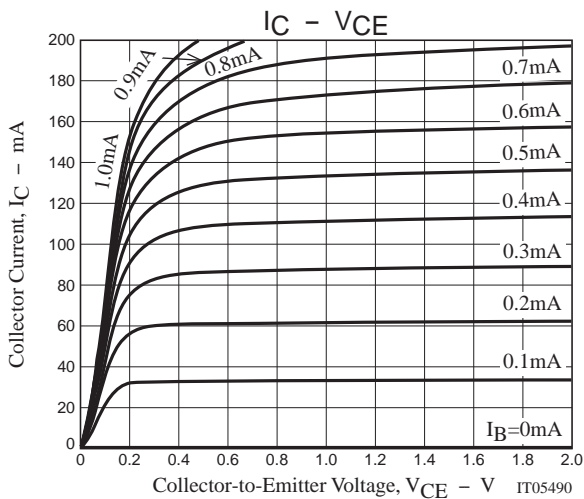
## Switching Time Test Circuit

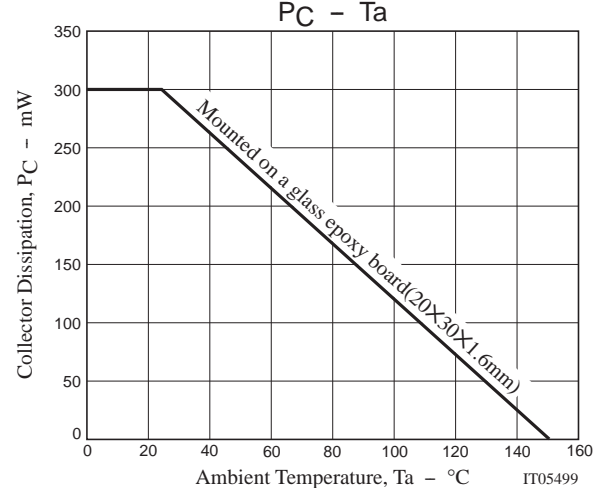
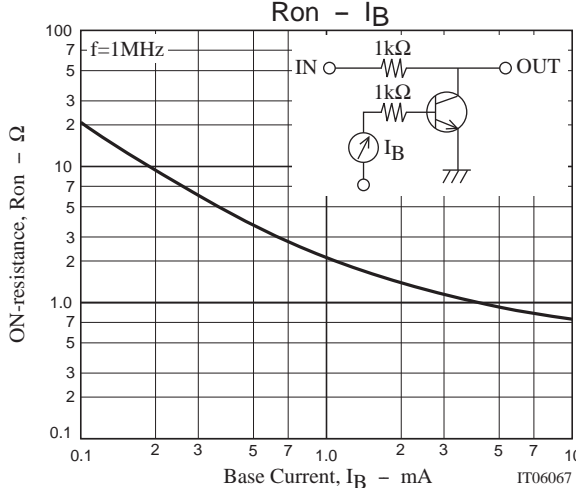
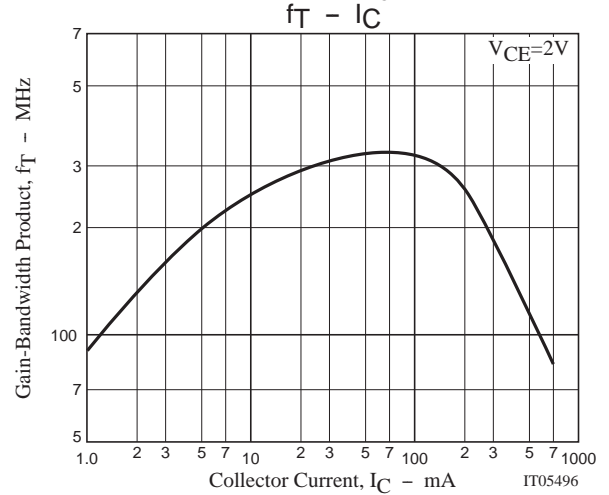
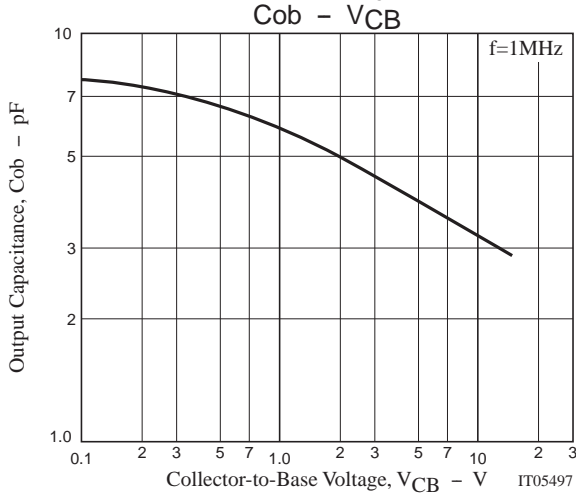
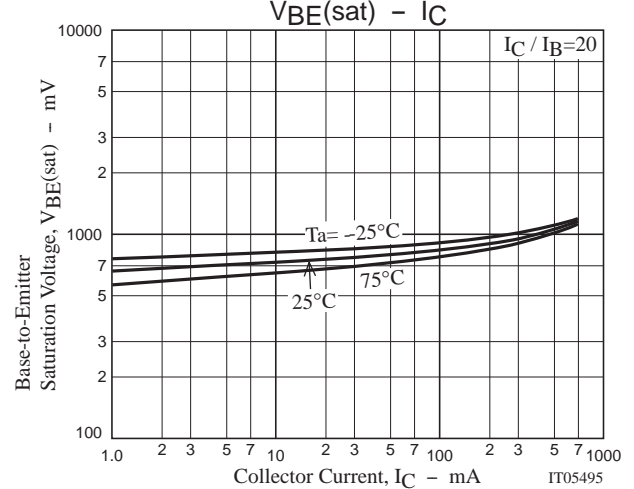
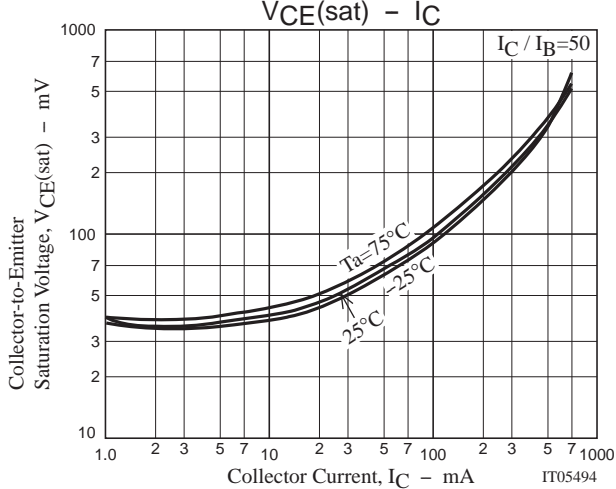
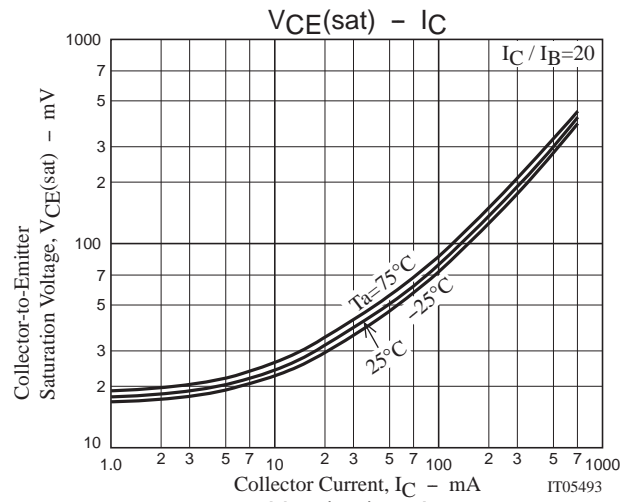
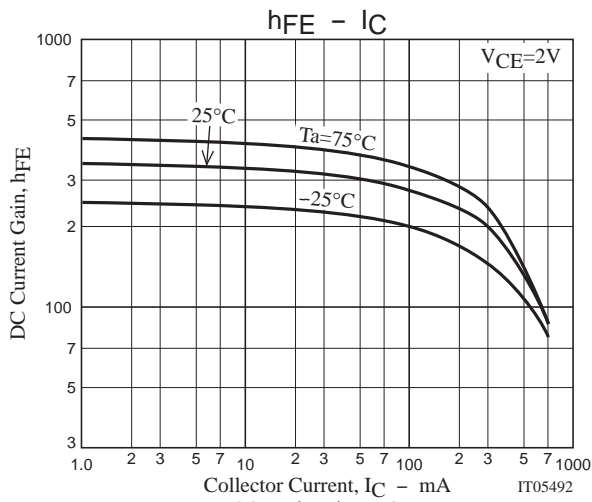


$$I_C = 20I_{B1} = -20I_{B2} = 500\text{mA}$$

## Ordering Information

Device	Package	Shipping	memo
15C01C-TB-E	CP	3,000pcs./reel	Pb Free





Embossed Taping Specification

15C01C-TB-E

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CP	CP	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label



NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



Those with one electrode terminal on the feed hole side.....TB

# 15C01C

## Outline Drawing

15C01C-TB-E



## Land Pattern Example



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